

# BC638

## PNP Epitaxial Silicon Transistor

### Switching and Amplifier Applications

- Complement to BC637



### Absolute Maximum Ratings T<sub>a</sub> = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CER</sub>	Collector-Emitter Voltage at R <sub>BE</sub> =1KΩ	-60	V
V <sub>CES</sub>	Collector-Emitter Voltage	-60	V
V <sub>CEO</sub>	Collector-Emitter Voltage	-60	V
V <sub>EBO</sub>	Emitter-Base Voltage	-5	V
I <sub>C</sub>	Collector Current	-1	A
I <sub>CP</sub>	Peak Collector Current	-1.5	A
I <sub>B</sub>	Base Current	-100	mA
P <sub>C</sub>	Collector Power Dissipation	1	W
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-65 ~ 150	°C

### Electrical Characteristics T<sub>a</sub> = 25°C unless otherwise noted

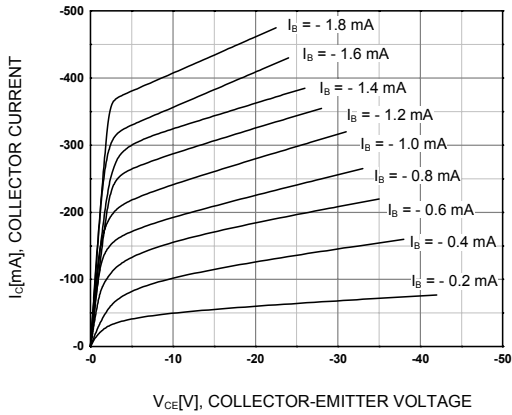
Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
BV <sub>CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = -10mA, I <sub>B</sub> =0	-60			V
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> = -30V, I <sub>E</sub> =0			-0.1	μA
I <sub>EBO</sub>	Emitter Cut-off Current	V <sub>EB</sub> = -5V, I <sub>C</sub> =0			-0.1	μA
h <sub>FE1</sub> h <sub>FE2</sub> h <sub>FE3</sub>	DC Current Gain	V <sub>CE</sub> = -2V, I <sub>C</sub> = -5mA V <sub>CE</sub> = -2V, I <sub>C</sub> = -150mA V <sub>CE</sub> = -2V, I <sub>C</sub> = -500mA	25 40 25		160	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = -500mA, I <sub>B</sub> = -50mA			-0.5	V
V <sub>BE</sub> (on)	Base-Emitter On Voltage	V <sub>CE</sub> = -2V, I <sub>C</sub> = -500mA			-1	V
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> = -5V, I <sub>C</sub> = -10mA, f=50MHz		100		MHz

**Package Marking and Ordering Information**

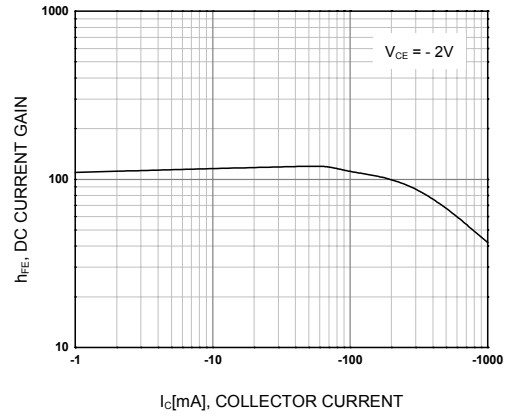
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
BC638	BC638BU	TO-92	--	--	10,000
BC638	BC638TA	TO-92	--	--	2,000
BC638	BC638TF	TO-92	--	--	2,000
BC638	BC638TFR	TO-92	--	--	2,000

## Typical Performance Characteristics

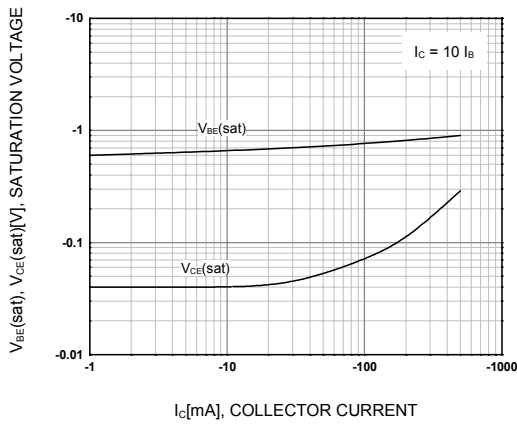
**Figure 1. Static Characteristic**



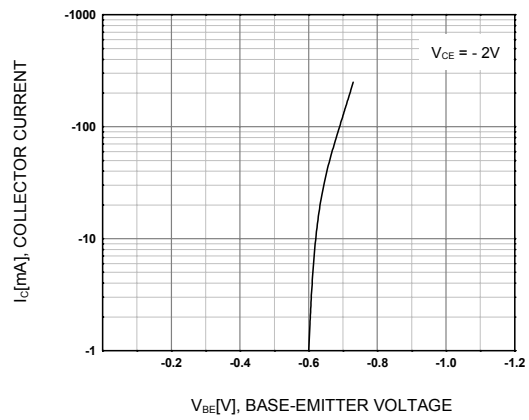
**Figure 2. DC Current Gain**



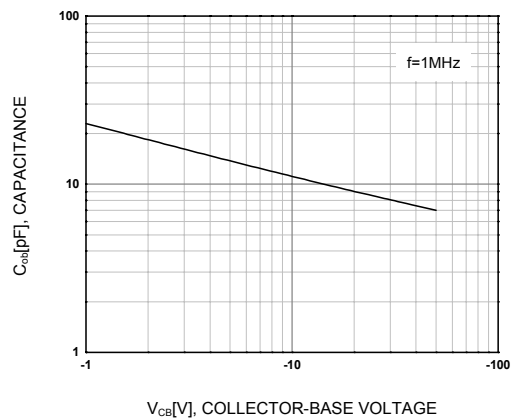
**Figure 3. Base-Emitter Saturation Voltage  
Collector-Emitter Saturation Voltage**



**Figure 4. Base-Emitter On Voltage**

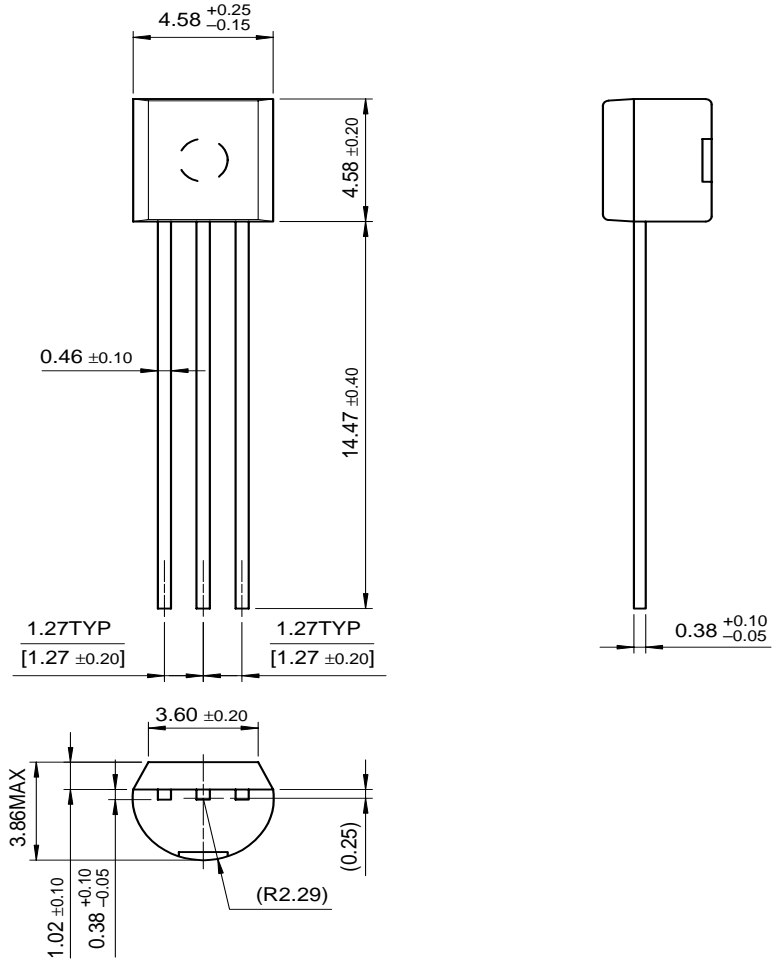


**Figure 5. Collector Output Capacitance**



Mechanical Dimensions

TO-92



Dimensions in Millimeters

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CROSSVOLT™	GTO™	MICROWIRE™	Quiet Series™	UHC™
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EcoSPARK™	I <sup>2</sup> C™	MSXPro™	RapidConnect™	UniFET™
E <sup>2</sup> C MOS™	i-Lo™	OCX™	μSerDes™	VCX™
EnSigna™	ImpliedDisconnect™	OCXPro™	SILENT SWITCHER®	Wire™
FACT™	IntelliMAX™	OPTOLOGIC®	SMART START™	
FACT Quiet Series™		OPTOPLANAR™	SPM™	
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Programmable Active Droop™		Power247™	SuperSOT™-3	
		PowerEdge™	SuperSOT™-6	

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